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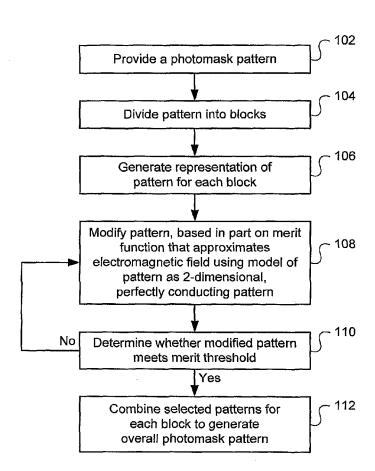
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[Continued on next page]

(54) Title: FAST SYSTEMS AND METHODS FOR CALCULATING ELECTROMAGNETIC FIELDS NEAR PHOTOMASKS



(57) Abstract: Photomask patterns represented using contours defined by mask functions. Given target pattern, contours are optimized such that defined photomask, when used in photolithographic process, prints wafer pattern faithful to target pattern. Optimization utilizes "merit function" for encoding aspects of photolithographic process, preferences relating to resulting pattern (e.g. restriction to rectilinear patterns), robustness against process variations, as well as restrictions imposed relating to practical and economic manufacturability of photomasks. Merit function may approximate electromagnetic field using model of mask pattern as infinitely thin, perfectly conducting pattern. Model may also be used for other lithographic methods, including simulation and verification.

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C. DOCUMENTS CONSIDERED TO BE RELEVANT				
Category *	Citation of document, with indication, where appropriate, of the relevant passages			Relevant to claim No.
X	US 2005/0191566 (Liu et al.) 01 September 2005 (01.09.2005), Whole document			1-3,7-9,13-16,20- 23,27-31
Y	US 6,756,980 B (Hayashi) 29 June 2004 (29.06.2004), Whole document.			4-6,10-12,17-19,24-26
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Further	documents are listed in the continuation of Box C.		See patent family annex.	
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